CMOS Voltage Regulator

1A



MD7601 Series is a high voltage (up to 40V) low power low dropout voltage regulator (LDO) manufactured in CMOS processes. It can deliver up to 1A of current while consuming only 12uA of quiescent current. It consists of a reference voltage generator, an error amplifier, a current foldback circuit, and a phase compensation circuit plus a driver transistor.

■ FEATURES

• Ultra-low Quiescent Current: 12uA

• Maximum Input Voltage: 40V

• Output Voltage Highly Accurate: ±2%

• Maximum Output Current: 1A

 Dropout Voltage: 10mV@I_{OUT}=10mA
 Temperature Stability: ±50ppm/°C
 Protections Circuits: Current Limiter, Foldback, Thermal shutdown

• Output Capacitor: Low ESR Ceramic

Capacitor Compatible

■ APPLICATIONS

- Smart wearer
- Long-life battery-powered devices
- Portable mobile devices, such as mobile phones, cameras, and so on
- Wireless communication equipment

■ Product Selections

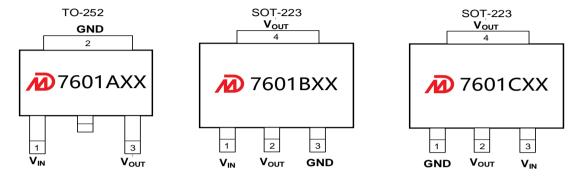
Туре	Output Voltage (note 1*)	Current Limit	Accuracy	Package (note 2*)	MARKING (note 3*)
MD7601A30	3.0V	1.8A	±2%	TO-252	№ 7601A30
MD7601A33	3.3V	1.8A	±2%	TO-252	₩7601A33
MD7601A36	3.6V	1.8A	±2%	TO-252	₹ 7601A36
MD7601A40	4.0V	1.8A	±2%	TO-252	№ 7601A40
MD7601A50	5.0V	1.8A	±2%	TO-252	№ 7601A50
MD7601A12	12.5V	1.8A	±2%	TO-252	№ 7601A12
MD7601B30	3.0V	1.8A	±2%	SOT-223	№ 7601B30
MD7601B33	3.3V	1.8A	±2%	SOT-223	₩7601B33
MD7601B36	3.6V	1.8A	±2%	SOT-223	№ 7601B36
MD7601B40	4.0V	1.8A	±2%	SOT-223	№ 7601B40
MD7601B50	5.0V	1.8A	±2%	SOT-223	№ 7601B50
MD7601B12	12.0V	1.8A	±2%	SOT-223	№ 7601B12
MD7601C30	3.0V	1.8A	±2%	SOT-223	№ 7601C30
MD7601C33	3.3V	1.8A	±2%	SOT-223	₩7601C33
MD7601C36	3.6V	1.8A	±2%	SOT-223	№ 7601C36
MD7601C40	4.0V	1.8A	±2%	SOT-223	№ 7601C40

MD7601C50	5.0V	1.8A	±2%	SOT-223	№ 7601C50
MD7601C12	12.0V	1.8A	±2%	SOT-223	₩7601C12

Notes:

- 1* Customer can request to customize the output voltage ranged from 1.2V to 15V if desired voltage is not found in the selections.
- 2* Customer can request customization of package choice.
- 3* Please pay attention to the MARKING of the product package type.

■ PIN CONFIGURATION (TOP VIEW)



■ Absolute Maximum Ratings (Unless otherwise indicated: T_a=25°C)

PARAMETER	SYMBOL	RATINGS	UNITS	
Input Voltage	V _{IN}	-0.3 ~ 45	V	
Output Voltage	V _{OUT}	Vss-0.3 ~ VIN+0.3V	V	
Power Dissipation	P _D	TO 252 1800 SOT 223 1500	mW	
Operating Ambient Temperature	T _{opr}	-40 ~ +85	°C	
Storage Temperature	T _{stg}	-40 ~ +125		
ESD Protection	ESD HBM	2000	V	

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

■ ELECTRICAL CHARACTERISTICS

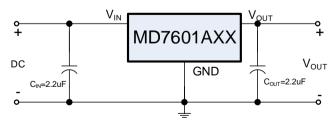
MD7601 Series (Unless otherwise indicated: T_a=25 °C)

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage*1	V _{OUT(S)}	V _{IN} = V _{OUT(S)} +2V, I _{OUT} =10mA		V _{OUT(S)} × 0.98	V _{OUT(S)}	V _{OUT(S)} × 1.02	V
Drangut Voltage*2	\ /	I _{OUT} =1mA			4	8	m\/
Dropout Voltage*2	V_{DROP}	Iout=1	Α		1000	1500	mV
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \bullet V_{OUT(s)}}$	V _{OUT(S)} +2V≤ I _{OUT} =1			0.01	0.02	%/V
Load Regulation		V _{IN} =V _{OUT(S)} +2V	V _{OUT(S)} ≤10V		20	80	- mV
Load Regulation	ΔV_{OUT2}	1mA≤l _{O∪T} ≤300mA	V _{OUT(S)} >10V		85	150	
Temperature Stability	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT(s)}}$	$V_{IN} = V_{OUT(S)} + 2V$, $I_{OUT} = 10$ mA -40°C \leq T _a \leq 85°C			±50		ppm/℃
	I _{GND}	no load	V _{OUT(S)} ≤10V		10	30	uA
GND Current			V _{OUT(S)} >10V		12	30	
		I _{OUT} =10	00mA		460		
Input Voltage	V _{IN}			2.2		40	V
Maximum Output Current	I _{OUTMAX}			1			
Current Limit*3	I _{LIM}	$V_{IN} = V_{OUT(S)} + 2V,$ $V_{OUT} = 0.95 \times V_{OUT(S)}$			1.8		А
Short Circuit Current*4	I _{SHORT}	V _{IN} =V _{OUT(S)} +2V	V _{OUT(S)} ≤10V		50		mA
		Vout=0V	V _{OUT(S)} >10V		75		IIIA
Power Supply Rejection Ratio	PSRR	f=10Hz, V _{OUT(S)} =3.6V			84		
		$f=100Hz$, $V_{OUT(S)}=3.6V$			80		dB
		$f=1kHz$, $V_{OUT(S)}=3.6V$			58		
Over Temperature Protection	ОТР	I _{OUT} =1mA			180		$^{\circ}$

Notes:

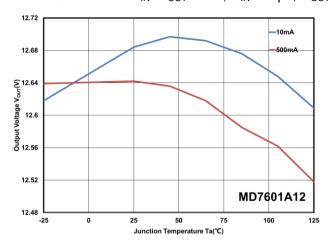
- V_{OUT(S)}: Output voltage when V_{IN}=V_{OUT}+2V, I_{OUT}=1 mA.
- 2. $V_{DROP}=V_{IN1}$ $(V_{OUT(S)} \times 0.98)$ where V_{IN1} is the input voltage when $V_{OUT}=V_{OUT(S)} \times 0.98$.
- 3. I_{LIM} : Output current when $V_{IN}=V_{OUT(S)}+2V$ and $V_{OUT}=0.95*V_{OUT(S)}$.
- 4. VOUT pin should be shorted to GND pin, and the impedance between them is less than 0.1 ohm.

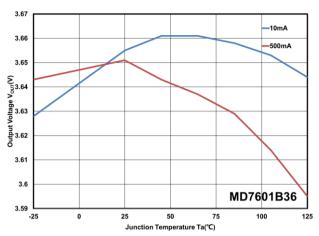
■ TYPICAL APPLICATIONS



Notes on Use

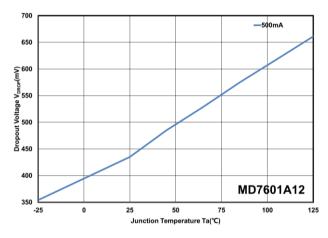
Input Capacitor (C_{IN}): 2.2 μ F above Output Capacitor (C_{OUT}): 2.2 μ F above

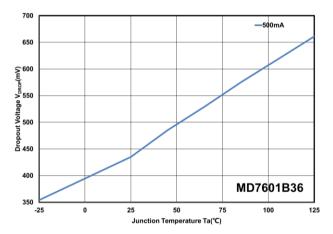




V_{OUT} vs Temperature at V_{OUT}=12V

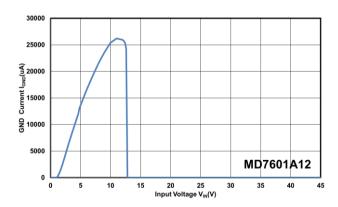
V_{OUT} vs Temperature at V_{OUT}=3.6V

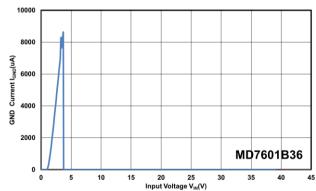




V_{DROP} vs Temperature at V_{OUT}=12V

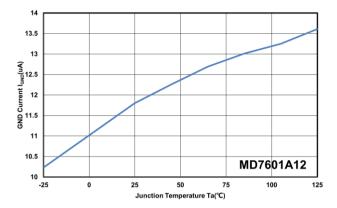
 V_{DROP} vs Temperature at V_{OUT} =3.6V



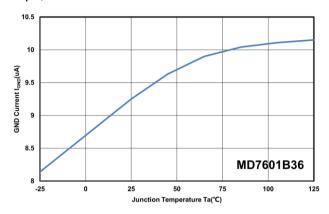


GND Current vs Input Voltage at Vout=12V

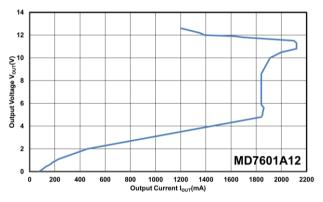
GND Current vs Input Voltage at Vout=3.6V



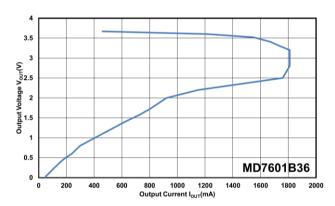
GND Current vs Temperature at V_{OUT}=12V



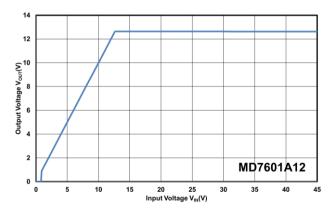
GND Current vs Temperature at V_{OUT}=3.6V



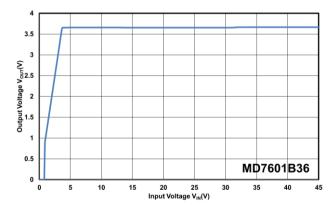
Output Current Fold-back at Vout=12V



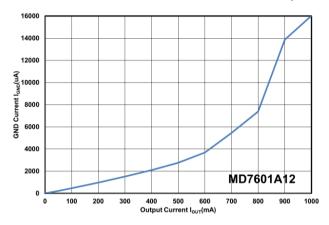
Output Current Fold-back at Vout=3.6V



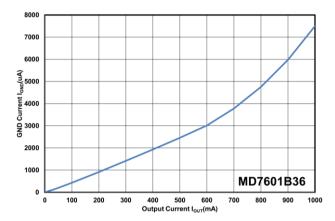
Output Voltage vs Input Voltage at Vout=12V



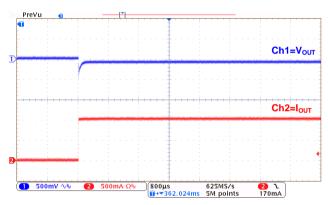
Output Voltage vs Input Voltage at V_{OUT}=3.6V



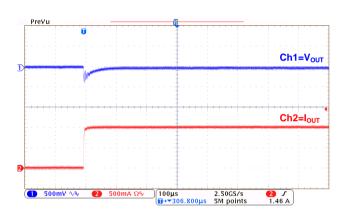
GND Current vs Output Current at Vout=12V



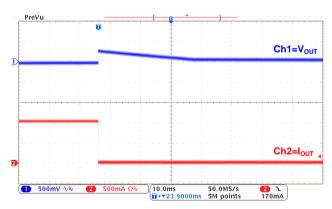
GND Current vs Output Current at V_{OUT}=3.6V



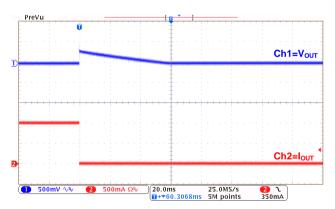
Load Transient at V_{OUT}=12V 7601A12(I_{OUT}=0mA~1A)



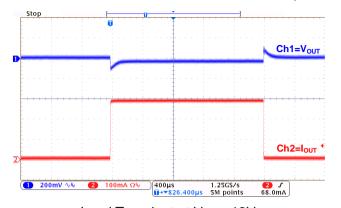
Load Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=0mA~1A)



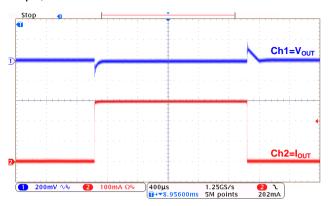
Load Transient at V_{OUT}=12V 7601A12(I_{OUT}=1A~0mA)



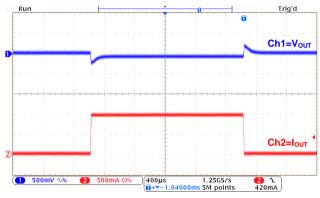
Load Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=1A~0mA)



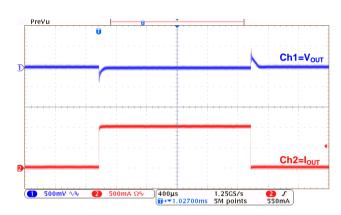
Load Transient at V_{OUT}=12V 7601A12(I_{OUT}=1mA~300mA~1mA)



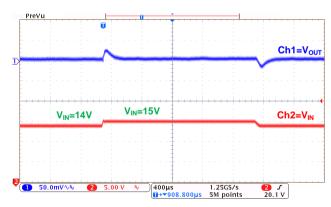
Load Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=1mA~300mA~1mA)



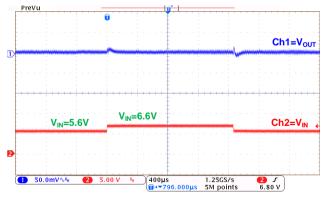
Load Transient at V_{OUT}=12V 7601A12(I_{OUT}=1mA~1A~1mA)



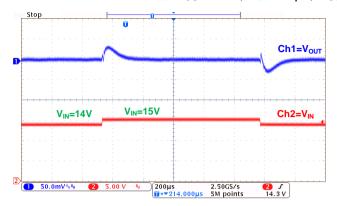
Load Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=1mA~1A~1mA)



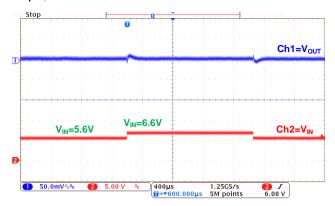
Line Transient at V_{OUT}=12V 7601A12(I_{OUT}=1mA)



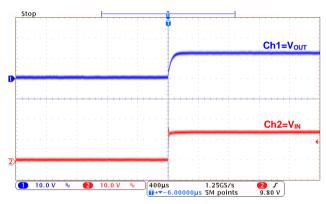
Line Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=1mA)



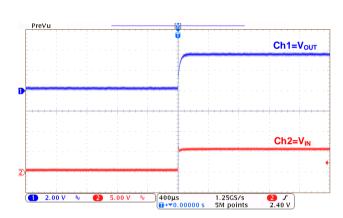
Line Transient at V_{OUT} =12V 7601A12(I_{OUT} =10mA)



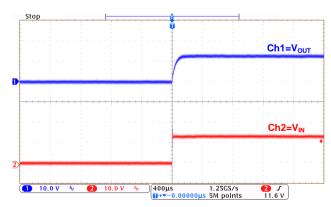
Line Transient at V_{OUT}=3.6V 7601B36(I_{OUT}=10mA)



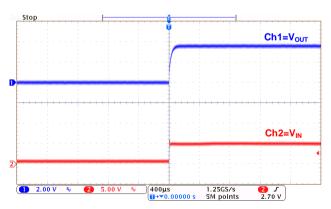
Power-Up at V_{OUT}=12V 7601A12(I_{OUT}=0mA)



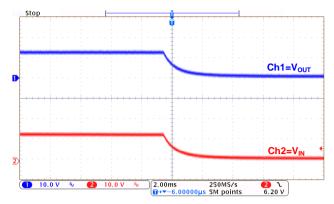
Power-Up at V_{OUT}=3.6V 7601B36(I_{OUT}=0mA)



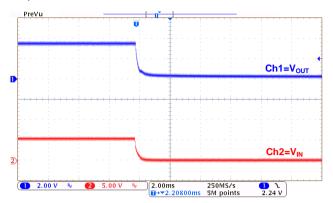
Power-Up at $V_{OUT}=12V$ 7601A12($I_{OUT}=1A$)



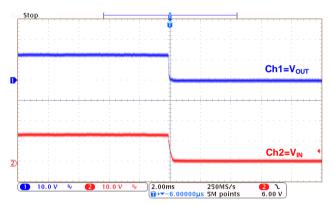
Power-Up at V_{OUT} =3.6V 7601B36(I_{OUT} =1A)



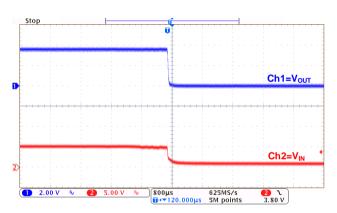
Power-Down at V_{OUT}=12V 7601A12(I_{OUT}=0mA)



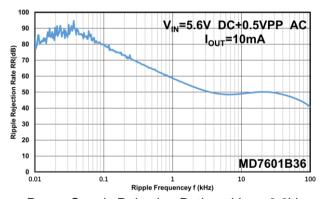
Power- Down at V_{OUT} =3.6V 7601B36(I_{OUT} =0mA)



Power- Down at $V_{OUT}=12V$ 7601A12($I_{OUT}=1A$)



Power- Down at V_{OUT} =3.6V 7601B36(I_{OUT} =1A)

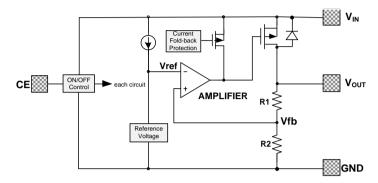


Power Supply Rejection Ratio at Vout=3.6V

■ OPERATIONAL EXPLANATION

1. Output voltage control

The voltage divided by resistors R1 and R2 is compared with the internal reference voltage by the error amplifier. The amplifier output then drives the P-channel MOSFET connected to the V_{OUT} pin. The output voltage at the V_{OUT} pin is regulated by this negative feedback system. The current limit circuit and short protect circuit operate in relation to output current level. Further, the IC's internal circuitry can be in operation or shutdown modes controlled by the CE pin's signal.



2. Pass transistor

The pass transistor with low turn-on resistance used in MD83XX is a P-channel MOSFET. If the potential on V_{OUT} pin is higher than VIN, it is possible that IC will be destroyed due to reverse current which is caused by parasitic diodes between V_{IN} and V_{OUT} . Therefore, the V_{OUT} pin potential exceeds V_{IN} +0.3V is not allowed.

3. Current foldback and over temperature protection

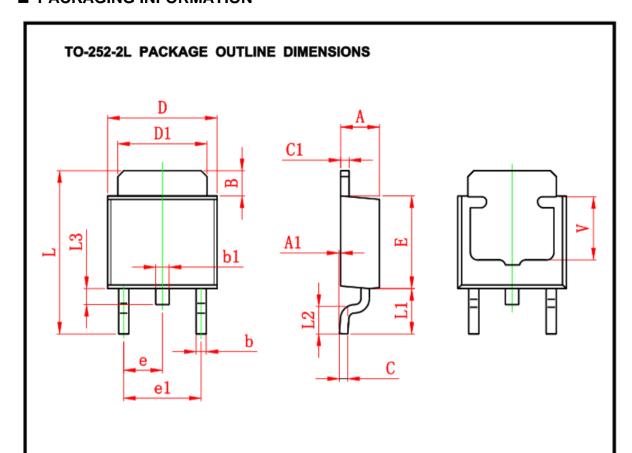
The MD83XX series includes a combination of a fixed current limiter circuit and a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases. This design can prevent the chip be damaged due to over temperature, moreover, the heat dissipation is limited by the package type.

Special attention should be paid to that the product of the dropout voltage on the chip and the output current must be smaller than the heat dissipation. If power consumption on the chip is more than the heat dissipation, OTP will protect the chip from damaging due to over temperature.

■ Notes:

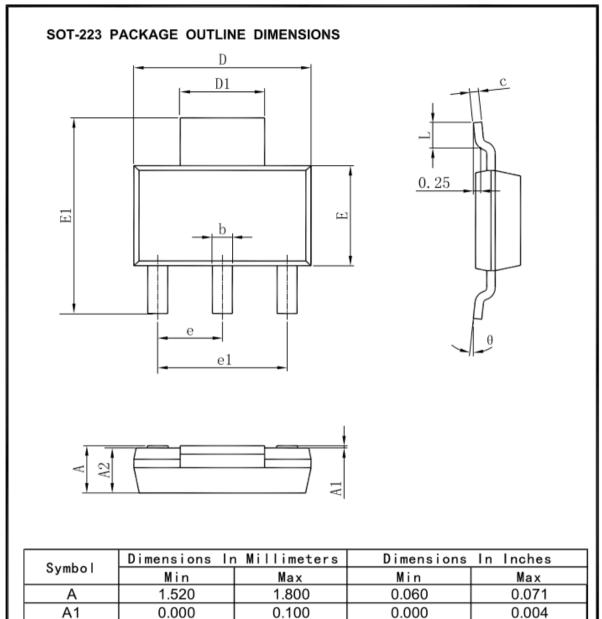
- 1. The input and output capacitors should be placed as close as possible to the IC.
- 2. If the impedance of the power supply is high, which is caused by forgetting installing input capacitor or installing too small value capacitor, the oscillation may occur.
- 3. Pay attention to the operation conditions of input and output voltage and load current, such that the power consumption in the IC should not exceed the allowable power consumption of the package even though the chip has short circuit protection.
- 4. IC has a built-in anti-static protection (ESD) circuit, but please do not add excessive stress to the IC.

■ PACKAGING INFORMATION



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	9.500	9.900	0.374	0.390	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1.780	0.055	0.070	
L3	0.600	0.900	0.024	0.035	
V	3.800 REF.		0.150	REF.	

■ PACKAGING INFORMATION(Continued)



Symbol	Dimensions In	Millimeters	Dimensions	In Inches	
Symbol	Min	Max	Min	Max	
Α	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
С	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300(BSC)		0.091(BSC)		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

For the newest datasheet, please see the website:

Version V1.5: 20210930

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